

BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC79M00 Series

THREE TERMINAL NEGATIVE VOLTAGE REGULATOR

μ PC79M00 series are monolithic three terminal negative regulators which employ internally current limiting, thermal shut down, output transistor safe operating area protection make them essentially indestructible.

They are intended as fixed voltage regulators in a wide range of application including local on card regulation for elimination of distribution problems associated wide single point regulation.

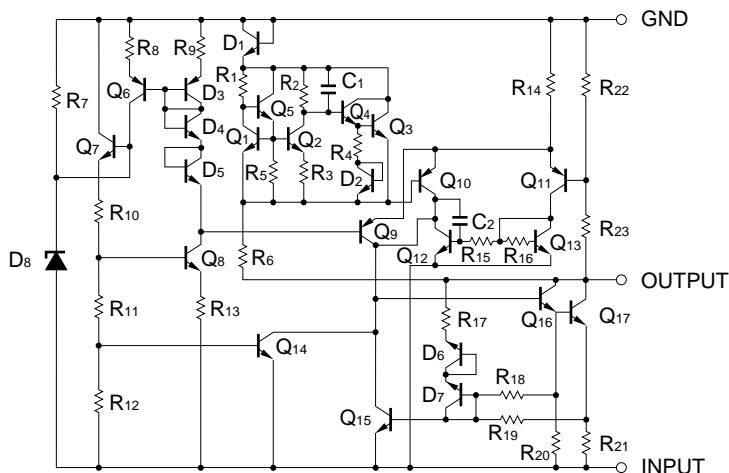
FEATURES

- Output current out of 500 mA.
- On-chip some protection circuit (over current protection, SOA protection and thermal shut down).
- Low noise.

★ ORDERING INFORMATION

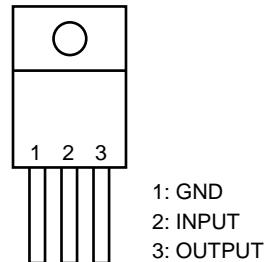
Part Number	Package	Output Voltage
μ PC79M05HF	3-pin plastic SIP (MP-45G) (isolated TO-220)	-5 V
μ PC79M08HF	3-pin plastic SIP (MP-45G) (isolated TO-220)	-8 V
μ PC79M12HF	3-pin plastic SIP (MP-45G) (isolated TO-220)	-12 V
μ PC79M15HF	3-pin plastic SIP (MP-45G) (isolated TO-220)	-15 V
μ PC79M18HF	3-pin plastic SIP (MP-45G) (isolated TO-220)	-18 V
μ PC79M24HF	3-pin plastic SIP (MP-45G) (isolated TO-220)	-24 V

EQUIVALENT CIRCUIT



PIN CONFIGURATION (Marking Side)

3-pin plastic SIP (MP-45G)



1: GND
2: INPUT
3: OUTPUT

The information in this document is subject to change without notice.

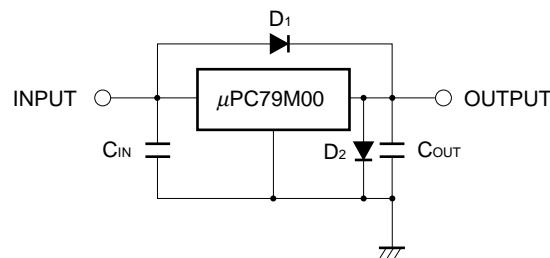
ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

Parameter	Symbol	Rating	Unit
Input Voltage	V _{IN}	-35/-40 ^{Note 1}	V
Internal Power Dissipation	P _T	15 ^{Note 2}	V
Operating Ambient Temperature	T _A	-20 to +85	°C
Operating Junction Temperature	T _J	-20 to +150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Thermal Resistance (junction to case)	R _{th(J-C)}	7	°C/W
Thermal Resistance (junction to ambient)	R _{th(J-A)}	65	°C/W

Notes 1. μ PC79M05, 08, 12, 15, 18: -35 V, μ PC79M24: -40 V

2. Internally limited. When operating junction temperature rise up to 150 °C, the internal circuit shutdown output voltage.

Caution Exposure to Absolute Maximum Ratings for extended periods may affect device reliability; exceeding the ratings could cause permanent damage. The parameters apply independently. The device should be operated within the limits specified under DC and AC Characteristics.

TYPICAL CONNECTION

C_{IN} : More than 2 μ F.

C_{OUT}: More than 1 μ F.

D₁ : Needed for V_{IN} > V_O.

D₂ : Needed for V_O > GND.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Part Number	MIN.	TYP.	MAX.	Unit
Input Voltage	V _{IN}	μ PC79M05	-7	-10	-25	V
		μ PC79M08	-10.5	-14	-25	
		μ PC79M12	-14.5	-19	-30	
		μ PC79M15	-17.5	-23	-30	
		μ PC79M18	-21	-27	-33	
		μ PC79M24	-27	-33	-38	
Output Current	I _O	All	5		350	mA
Operating Junction Temperature	T _J	All	-20		+125	°C

ELECTRICAL CHARACTERISTICS

 μ PC79M05(V_{IN} = -10 V, I_O = 350 mA, 0 °C ≤ T_J ≤ +125 °C, C_{IN} = 2.2 μF, C_{OUT} = 1 μF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V _O	T _J = 25 °C	-4.8	-5.0	-5.2	V
		-7 V ≤ V _{IN} ≤ -25 V, 5 mA ≤ I _O ≤ 350 mA	-4.75		-5.25	
Line Regulation	REG _{IN}	T _J = 25 °C, -7 V ≤ V _{IN} ≤ -25 V		18	50	mV
		T _J = 25 °C, -8 V ≤ V _{IN} ≤ -18 V		10	30	
Load Regulation	REG _L	T _J = 25 °C, 5 mA ≤ I _O ≤ 500 mA		15	100	mV
		T _J = 25 °C, 5 mA ≤ I _O ≤ 350 mA		10		
Quiescent Current	I _{BIAS}	T _J = 25 °C		4.3	6.0	mA
Quiescent Current Change	ΔI _{BIAS}	-8 V ≤ V _{IN} ≤ -25 V			0.5	mA
		5 mA ≤ I _O ≤ 350 mA			0.4	
Output Noise Voltage	V _n	T _J = 25 °C, 10 Hz ≤ f ≤ 100 kHz		45	200	μV _{r.m.s.}
Ripple Rejection	R • R	T _J = 25 °C, f = 120 Hz, -8 V ≤ V _{IN} ≤ -18 V, I _O = 100 mA	50	72		dB
Dropout Voltage	V _{DIF}	T _J = 25 °C		1.1		V
Short Circuit Current	I _{Oshort}	T _J = 25 °C, V _{IN} = -25 V		500		mA
Peak Output Current	I _{Opeak}	T _J = 25 °C	620	880	1 020	mA
Temperature Coefficient of Output Voltage	ΔV _O /ΔT	I _O = 5 mA		0.2		mV/°C

 μ PC79M08(V_{IN} = -14 V, I_O = 350 mA, 0 °C ≤ T_J ≤ +125 °C, C_{IN} = 2.2 μF, C_{OUT} = 1 μF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V _O	T _J = 25 °C	-7.7	-8.0	-8.3	V
		-10.5 V ≤ V _{IN} ≤ -25 V, 5 mA ≤ I _O ≤ 350 mA	-7.6		-8.4	
Line Regulation	REG _{IN}	T _J = 25 °C, -10.5 V ≤ V _{IN} ≤ -25 V		20	80	mV
		T _J = 25 °C, -11 V ≤ V _{IN} ≤ -21 V		15	50	
Load Regulation	REG _L	T _J = 25 °C, 5 mA ≤ I _O ≤ 500 mA		20	160	mV
		T _J = 25 °C, 5 mA ≤ I _O ≤ 350 mA		15		
Quiescent Current	I _{BIAS}	T _J = 25 °C		4.3	6.0	mA
Quiescent Current Change	ΔI _{BIAS}	-10.5 V ≤ V _{IN} ≤ -25 V			0.5	mA
		5 mA ≤ I _O ≤ 350 mA			0.4	
Output Noise Voltage	V _n	T _J = 25 °C, 10 Hz ≤ f ≤ 100 kHz		65	220	μV _{r.m.s.}
Ripple Rejection	R • R	T _J = 25 °C, f = 120 Hz, -11.5 V ≤ V _{IN} ≤ -21.5 V, I _O = 100 mA	50	66		dB
Dropout Voltage	V _{DIF}	T _J = 25 °C		1.1		V
Short Circuit Current	I _{Oshort}	T _J = 25 °C, V _{IN} = -25 V		500		mA
Peak Output Current	I _{Opeak}	T _J = 25 °C	620	880	1 020	mA
Temperature Coefficient of Output Voltage	ΔV _O /ΔT	I _O = 5 mA		0.3		mV/°C

μ PC79M12(V_{IN} = -19 V, I_O = 350 mA, 0 °C ≤ T_J ≤ +125 °C, C_{IN} = 2.2 μF, C_{OUT} = 1 μF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V _O	T _J = 25 °C	-11.5	-12	-12.5	V
		-14.5 V ≤ V _{IN} ≤ -30 V, 5 mA ≤ I _O ≤ 350 mA	-11.4		-12.6	
Line Regulation	REG _{IN}	T _J = 25 °C, -14.5 V ≤ V _{IN} ≤ -30 V		25	80	mV
		T _J = 25 °C, -15 V ≤ V _{IN} ≤ -25 V		20	50	
Load Regulation	REG _L	T _J = 25 °C, 5 mA ≤ I _O ≤ 500 mA		35	240	mV
		T _J = 25 °C, 5 mA ≤ I _O ≤ 350 mA		25		
Quiescent Current	I _{BIAS}	T _J = 25 °C		4.4	6.0	mA
Quiescent Current Change	ΔI _{BIAS}	-14.5 V ≤ V _{IN} ≤ -30 V			0.5	mA
		5 mA ≤ I _O ≤ 350 mA			0.4	
Output Noise Voltage	V _n	T _J = 25 °C, 10 Hz ≤ f ≤ 100 kHz		125	280	μV _{r.m.s.}
Ripple Rejection	R • R	T _J = 25 °C, f = 120 Hz, -15 V ≤ V _{IN} ≤ -25 V, I _O = 100 mA	50	64		dB
Dropout Voltage	V _{DIF}	T _J = 25 °C		1.1		V
Short Circuit Current	I _{Oshort}	T _J = 25 °C, V _{IN} = -30 V		400		mA
Peak Output Current	I _{Opeak}	T _J = 25 °C	620	880	1 020	mA
Temperature Coefficient of Output Voltage	ΔV _O /ΔT	I _O = 5 mA		0.4		mV/°C

 μ PC79M15(V_{IN} = -23 V, I_O = 350 mA, 0 °C ≤ T_J ≤ +125 °C, C_{IN} = 2.2 μF, C_{OUT} = 1 μF, unless otherwise specified)

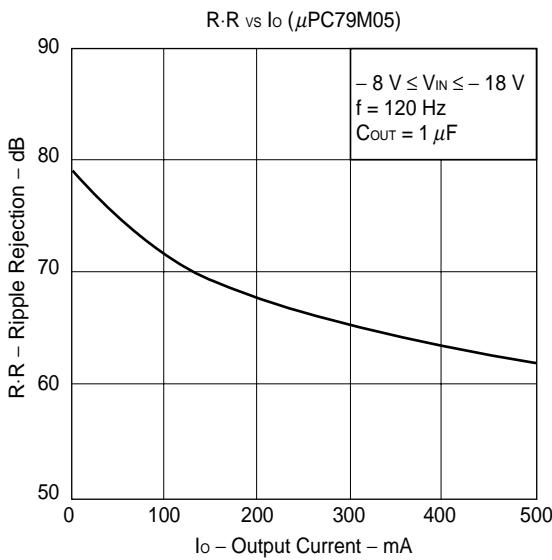
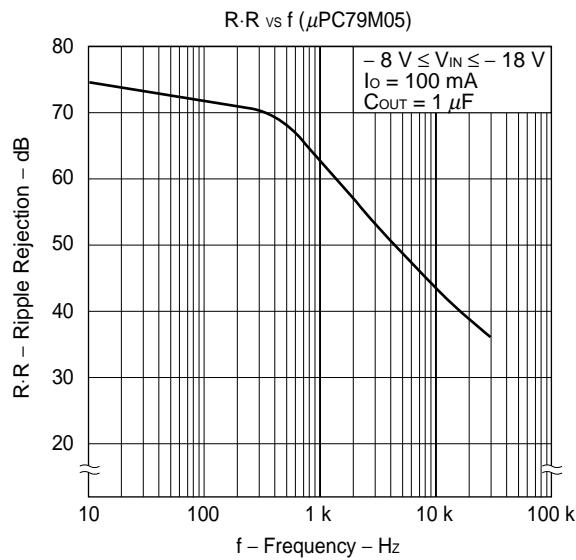
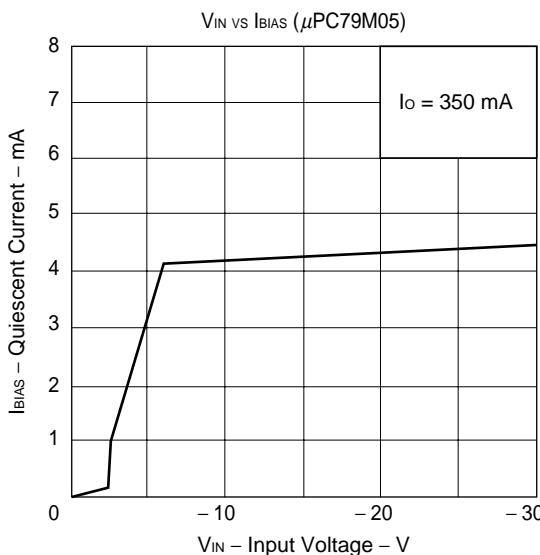
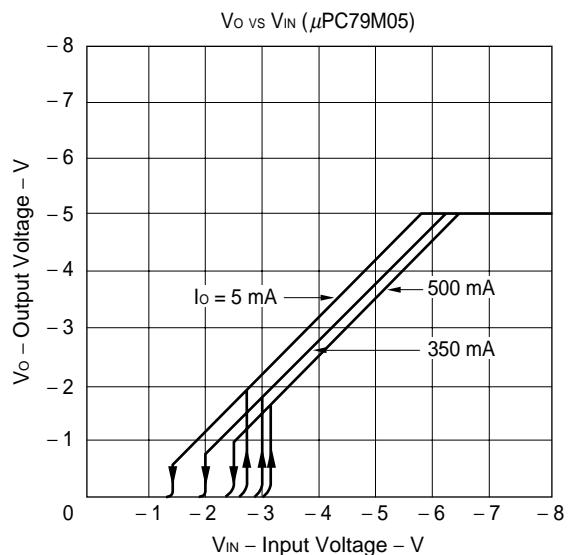
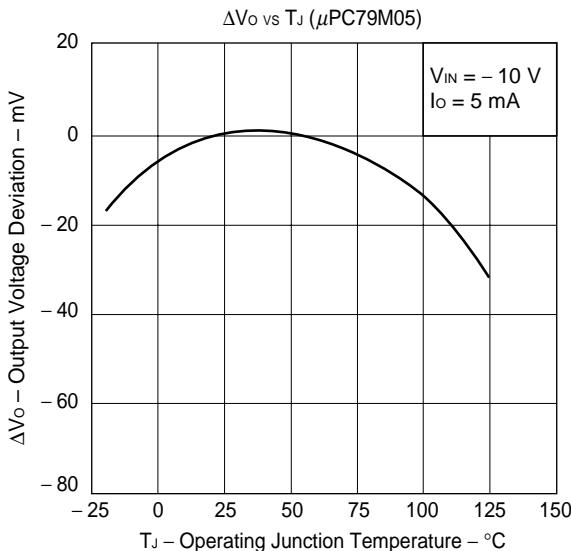
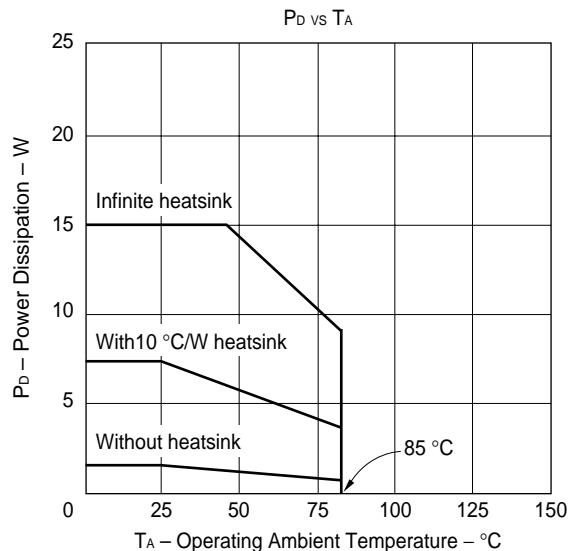
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V _O	T _J = 25 °C	-14.4	-15	-15.6	V
		-17.5 V ≤ V _{IN} ≤ -30 V, 5 mA ≤ I _O ≤ 350 mA	-14.25		-15.75	
Line Regulation	REG _{IN}	T _J = 25 °C, -17.5 V ≤ V _{IN} ≤ -30 V		30	80	mV
		T _J = 25 °C, -18 V ≤ V _{IN} ≤ -28 V		25	50	
Load Regulation	REG _L	T _J = 25 °C, 5 mA ≤ I _O ≤ 500 mA		50	240	mV
		T _J = 25 °C, 5 mA ≤ I _O ≤ 350 mA		35		
Quiescent Current	I _{BIAS}	T _J = 25 °C		4.4	6.0	mA
Quiescent Current Change	ΔI _{BIAS}	-17.5 V ≤ V _{IN} ≤ -30 V			0.5	mA
		5 mA ≤ I _O ≤ 350 mA			0.4	
Output Noise Voltage	V _n	T _J = 25 °C, 10 Hz ≤ f ≤ 100 kHz		150	360	μV _{r.m.s.}
Ripple Rejection	R • R	T _J = 25 °C, f = 120 Hz, -18.5 V ≤ V _{IN} ≤ -28.5 V, I _O = 100 mA	50	62		dB
Dropout Voltage	V _{DIF}	T _J = 25 °C		1.1		V
Short Circuit Current	I _{Oshort}	T _J = 25 °C, V _{IN} = -30 V		400		mA
Peak Output Current	I _{Opeak}	T _J = 25 °C	620	880	1 020	mA
Temperature Coefficient of Output Voltage	ΔV _O /ΔT	I _O = 5 mA		0.6		mV/°C

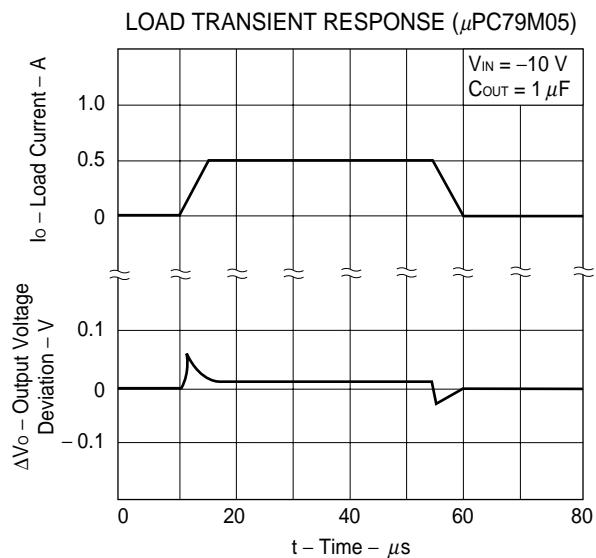
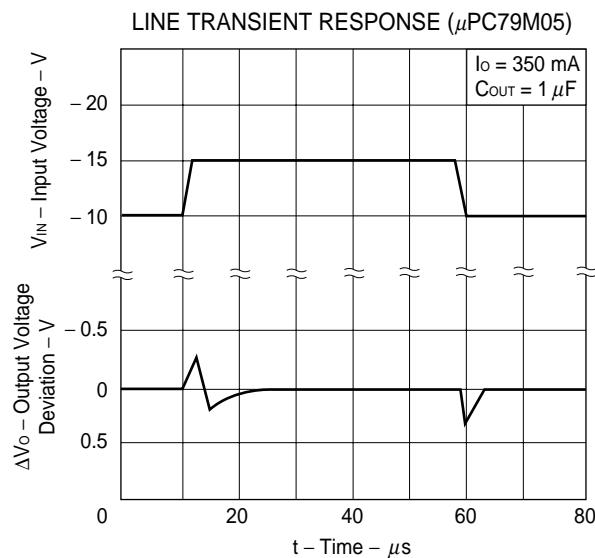
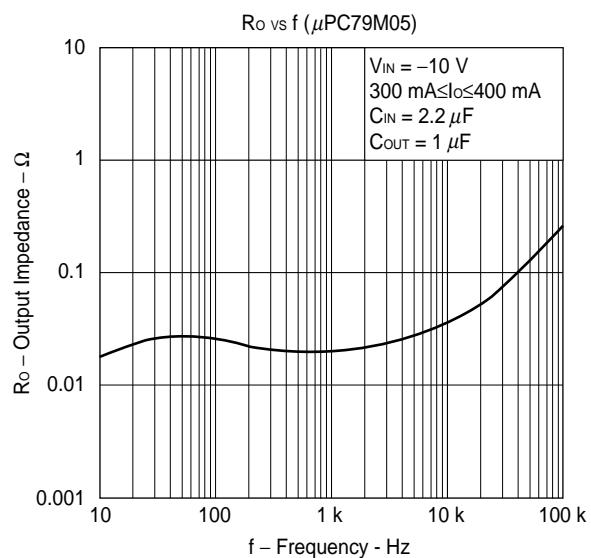
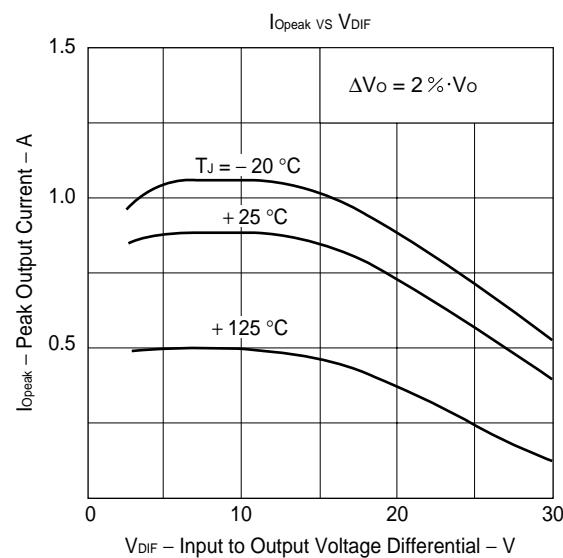
μ PC79M18(V_{IN} = -27 V, I_O = 350 mA, 0 °C ≤ T_J ≤ +125 °C, C_{IN} = 2.2 μF, C_{OUT} = 1 μF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V _O	T _J = 25 °C	-17.3	-18	-18.7	V
		-21 V ≤ V _{IN} ≤ -33 V, 5 mA ≤ I _O ≤ 350 mA	-17.1		-18.9	
Line Regulation	REG _{IN}	T _J = 25 °C, -21 V ≤ V _{IN} ≤ -33 V		30	80	mV
		T _J = 25 °C, -24 V ≤ V _{IN} ≤ -30 V		25	50	
Load Regulation	REG _L	T _J = 25 °C, 5 mA ≤ I _O ≤ 500 mA		60	300	mV
		T _J = 25 °C, 5 mA ≤ I _O ≤ 350 mA		45		
Quiescent Current	I _{BIAS}	T _J = 25 °C		4.4	6.0	mA
Quiescent Current Change	ΔI _{BIAS}	-21 V ≤ V _{IN} ≤ -33 V			0.5	mA
		5 mA ≤ I _O ≤ 350 mA			0.4	
Output Noise Voltage	V _n	T _J = 25 °C, 10 Hz ≤ f ≤ 100 kHz		200	440	μV _{r.m.s.}
Ripple Rejection	R • R	T _J = 25 °C, f = 120 Hz, -22 V ≤ V _{IN} ≤ -32 V, I _O = 100 mA	50	60		dB
Dropout Voltage	V _{DIF}	T _J = 25 °C		1.1		V
Short Circuit Current	I _{Oshort}	T _J = 25 °C, V _{IN} = -33 V		350		mA
Peak Output Current	I _{Opeak}	T _J = 25 °C	620	880	1 020	mA
Temperature Coefficient of Output Voltage	ΔV _O /ΔT	I _O = 5 mA		0.8		mV/°C

 μ PC79M24(V_{IN} = -33 V, I_O = 350 mA, 0 °C ≤ T_J ≤ +125 °C, C_{IN} = 2.2 μF, C_{OUT} = 1 μF, unless otherwise specified)

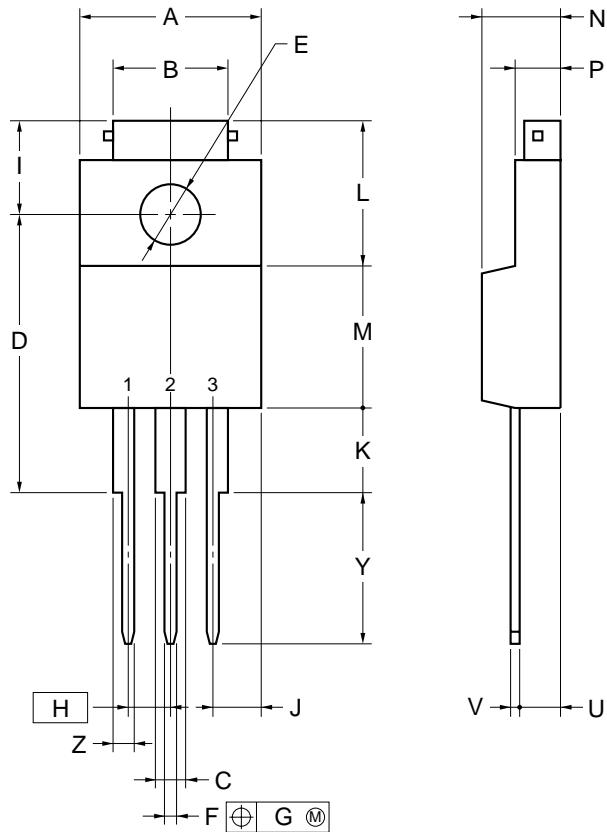
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V _O	T _J = 25 °C	-23.0	-24	-25.0	V
		-27 V ≤ V _{IN} ≤ -38 V, 5 mA ≤ I _O ≤ 350 mA	-22.8		-25.2	
Line Regulation	REG _{IN}	T _J = 25 °C, -27 V ≤ V _{IN} ≤ -38 V		30	80	mV
		T _J = 25 °C, -30 V ≤ V _{IN} ≤ -36 V		25	50	
Load Regulation	REG _L	T _J = 25 °C, 5 mA ≤ I _O ≤ 500 mA		80	360	mV
		T _J = 25 °C, 5 mA ≤ I _O ≤ 350 mA		50		
Quiescent Current	I _{BIAS}	T _J = 25 °C		4.5	6.0	mA
Quiescent Current Change	ΔI _{BIAS}	-27 V ≤ V _{IN} ≤ -38 V			0.5	mA
		5 mA ≤ I _O ≤ 350 mA			0.4	
Output Noise Voltage	V _n	T _J = 25 °C, 10 Hz ≤ f ≤ 100 kHz		250	600	μV _{r.m.s.}
Ripple Rejection	R • R	T _J = 25 °C, f = 120 Hz, -28 V ≤ V _{IN} ≤ -38 V, I _O = 100 mA	50	57		dB
Dropout Voltage	V _{DIF}	T _J = 25 °C		1.1		V
Short Circuit Current	I _{Oshort}	T _J = 25 °C, V _{IN} = -38 V		200		mA
Peak Output Current	I _{Opeak}	T _J = 25 °C	620	880	1 020	mA
Temperature Coefficient of Output Voltage	ΔV _O /ΔT	I _O = 5 mA		1.0		mV/°C

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)



PACKAGE DRAWINGS

3PIN PLASTIC SIP (MP-45G)



NOTE

Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	10.4 MAX.	0.410 MAX.
B	7.0	0.276
C	1.2 MIN.	0.047 MIN.
D	17.0 ± 0.3	$0.669^{+0.013}_{-0.012}$
E	$\phi 3.3 \pm 0.2$	$\phi 0.130 \pm 0.008$
F	0.75 ± 0.10	$0.030^{+0.004}_{-0.005}$
G	0.25	0.010
H	2.54 (T.P.)	0.100 (T.P.)
I	5.0 ± 0.3	0.197 ± 0.012
J	2.66 MAX.	0.105 MAX.
K	4.8 MIN.	0.188 MIN.
L	8.5	0.335
M	8.5	0.335
N	4.5 ± 0.2	0.177 ± 0.008
P	2.8 ± 0.2	$0.110^{+0.009}_{-0.008}$
U	2.4 ± 0.5	$0.094^{+0.021}_{-0.020}$
V	0.65 ± 0.10	$0.026^{+0.004}_{-0.005}$
Y	8.9 ± 0.7	0.350 ± 0.028
Z	1.0 MIN.	0.039 MIN.

P3HF-254B-3

RECOMMENDED SOLDERING CONDITIONS

When soldering these products, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

For more details, refer to our document “**SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL**” (**C10535E**).

Type of Through-hole Devices

μ PC79M05HF, 79M08HF, 79M12HF, 79M15HF, 79M18HF, 79M24HF: 3-pin plastic SIP (MP-45G)

Process	Conditions
Wave soldering (only to leads)	Solder temperature: 260 °C or below, Flow time: 10 seconds or less.

Caution For through-hole device, the wave soldering process must be applied only to leads, and make sure that the package body does not get jet soldered.

★ REFERENCE DOCUMENTS

Quality Grades on NEC Semiconductor Devices	C11531E
Semiconductor Device Mounting Technology Manual	C10535E
IC Package Manual	C10943X
Guide to Quality Assurance for Semiconductor Devices	MEI-1202
Semiconductors Selection Guide	X10679E
NEC Semiconductor Device Reliability/Quality Control System -Three Terminal Regulator	IEI-1212

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The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

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NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

Anti-radioactive design is not implemented in this product.